NSN 5962-01-273-6549

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View Online at https://aerobasegroup.com/nsn/5962-01-273-6549

View Offiline at https://derobasegroup.com/nsi//0302-01-270-0343
Body Length:
Between 0.970 inches and 1.019 inches
Body Width:
Between 0.280 inches and 0.300 inches
Body Height:
Between 0.115 inches and 0.155 inches
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and burn in and programmable and 3-state output
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
10 input
Case Outline Source And Designator:
D-8 mil-m-38510
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
7.0 volts power source
Time Rating Per Chacteristic:
80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, high to low leve
output
Memory Device Type:
Prom
Memory Capacity:
Unknown
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
20 printed circuit
Shelf Life:
N/a
Unit Of Measure:

Demilitarization: Yes - demil/mli

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